

### 2.0A SBR® SURFACE MOUNT SUPER BARRIER RECTIFIER PowerDl® 123

#### **Features**

- Low Forward Voltage Drop
- Low Leakage Current
- Superior Reverse Avalanche Capability
- **Excellent High Temperature Stability**
- Patented Interlocking Clip Design for High Surge Current Capacity
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- ±16KV ESD Protection (HBM, 3B)
- ±25KV ESD Protection (IEC61000-4-2 Level 4, Air Discharge)
- Lead Free Finish, RoHS Compliant (Note 1)
- "Green" Molding Compound (No Br, Sb)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: PowerDI®123
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Polarity Indicator: Cathode Band
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 🙉
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.018 grams (approximate)



Top View

### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	30	٧
RMS Reverse Voltage	V <sub>RM</sub> V <sub>R(RMS)</sub>	21	V
Average Rectified Output Current (See Figure 1)	Io	2.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	75	А

### Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Thermal Resistance Junction to Soldering (Note 2) Thermal Resistance Junction to Ambient (Note 3) Thermal Resistance Junction to Ambient (Note 4)	$egin{array}{c} R_{ heta JS} \ R_{ heta JA} \ R_{ heta JA} \end{array}$	5 175 100	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

Notes:

- 1. RoHS revision 13.2.2003. High temperature solder exemption applied, see EU Directive Annex Note 7.
- 2. Theoretical R<sub>BIS</sub> calculated from the top center of the die straight down to the PCB cathode tab solder junction.
- 3. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.

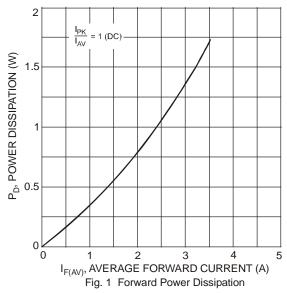
4. Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.

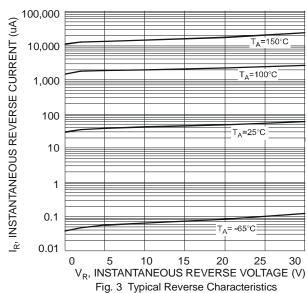


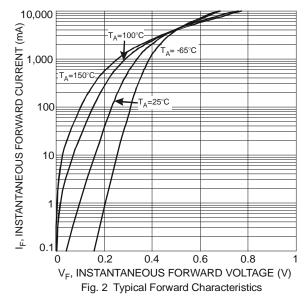
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 5)	V <sub>(BR)R</sub>	30	-	-	V	I <sub>R</sub> = 250μA
Forward Voltage Drop	V <sub>F</sub>	- - - - -	0.23 0.34 0.40 0.50 0.13 0.275	0.28 0.39 0.45 - 0.19 0.33	V	I <sub>F</sub> = 0.1A, T <sub>J</sub> = 25°C I <sub>F</sub> = 1.0A, T <sub>J</sub> = 25°C I <sub>F</sub> = 2.0A, T <sub>J</sub> = 25°C I <sub>F</sub> = 4.0A, T <sub>J</sub> = 125°C I <sub>F</sub> = 0.1A, T <sub>J</sub> = 125°C I <sub>F</sub> = 1.0A, T <sub>J</sub> = 125°C
Leakage Current (Note 5)	I <sub>R</sub>	-	50 55 5 7	100 200 10 15	μΑ μΑ mA mA	$V_R = 5V, T_J = 25^{\circ}C$ $V_R = 30V, T_J = 25^{\circ}C$ $V_R = 5V, T_J = 125^{\circ}C$ $V_R = 30V, T_J = 125^{\circ}C$

Notes: 5. Short duration pulse test used to minimize self-heating effect.

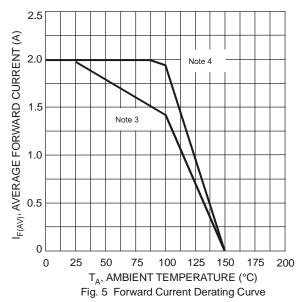


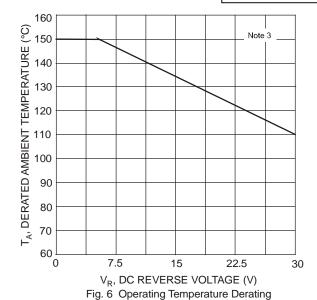


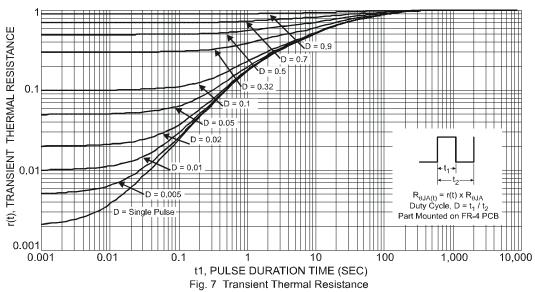


10,000 f = 1MHzC<sub>T</sub>, TOTAL CAPACITANCE (pF) 1,000 100 10 15 20 V<sub>R</sub>, DC REVERSE VOLTAGE (V) Fig. 4 Total Capacitance vs. Reverse Voltage







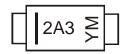


## Ordering Information (Note 6)

- 1			
	Part Number	Case	Packaging
	SBR2A30P1-7	PowerDI <sup>®</sup> 123	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



2A3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

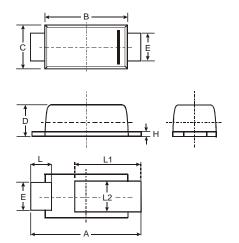
Date Code Key

Year	2006	2007	20	80	2009	2010	2011	2012	2 20	13	2014	2015
Code	Т	U	\	<b>V</b>	W	Χ	Υ	Z		4	В	С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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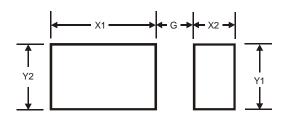


### **Package Outline Dimensions**



PowerDI <sup>®</sup> 123					
Dim	Min	Max	Тур		
Α	3.50	3.90	3.70		
В	2.60	3.00	2.80		
С	1.63	1.93	1.78		
D	0.93	1.00	0.98		
Е	0.85	1.25	1.00		
Н	0.15	0.25	0.20		
L	0.55	0.75	0.65		
L1	1.80	2.20	2.00		
L2	0.95	1.25	1.10		
All D	All Dimensions in mm				

## **Suggested Pad Layout**



Dimensions	Value (in mm)
G	1.0
X1	2.2
X2	0.9
Y1	1.4
Y2	1.4

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